			·	
_	215	(((438/166) or (438/486) or	USPAT;	2002/06/08 14:43
		(438/476)).CCLS.) and getter\$3	US-PGPUB	
-	28	((((438/166) or (438/486) or	USPAT;	2002/06/08 14:43
	İ	(438/476)).CCLS.) and getter\$3) and (inert	US-PGPUB	
		or noble) adj gas		
-	9	(((((438/166) or (438/486) or	USPAT;	2002/06/08 14:44
		(438/476)).CCLS.) and getter\$3) and (inert	US-PGPUB	
		or noble) adj gas) and barrier		
-	0	("FOR0146").PN.	USPAT;	2002/06/08 14:08
			US-PGPUB	
-	0	("FOR0146").PN.	JPO;	2002/06/10 19:02
			DERWENT;	
			IBM_TDB	
-	96	((((438/166) or (438/486) or	USPAT;	2002/06/08 14:43
		(438/476)).CCLS.) and getter\$3) and	US-PGPUB	
		amorphous		
-	16	(((((438/166) or (438/486) or	USPAT;	2002/06/08 14:43
		(438/476)).CCLS.) and getter\$3) and	US-PGPUB	
		amorphous) and (inert or noble) adj gas		
-	6	((((((438/166) or (438/486) or	USPAT;	2002/06/08 14:44
		(438/476)).CCLS.) and getter\$3) and	US-PGPUB	
		amorphous) and (inert or noble) adj gas)		[
		and barrier		
-	1	("6396147").PN.	USPAT;	2002/06/10 17:37
			US-PGPUB	
-	1	("5789284").PN.	USPAT;	2002/06/10 17:37
			US-PGPUB	
-	0	("FOR 146").PN.	JPO;	2002/06/10 19:04
			DERWENT;	
			IBM_TDB	
-	9	(metallic or(metal\$4 adj (cluster\$1 or	USPAT;	2002/06/21 16:53
		element\$1))) with (anneal\$ with (electric	US-PGPUB;	
		adj current))	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	1	("20020086469").PN.	USPAT;	2003/06/02 17:02
			US-PGPUB	
-	19346	kim.in.	USPAT;	2003/06/02 17:02
		0.2	US-PGPUB	
-	8679	getter\$3	USPAT;	2003/06/02 17:03
			US-PGPUB	
-	44	kim.in. and getter\$3	USPAT;	2003/06/02 17:03
	1.000		US-PGPUB	2002/06/02 12:50
-	16337	getter\$3 or getter	USPAT;	2003/06/03 13:50
	1		US-PGPUB;	
			EPO; JPO;	
	1	·	DERWENT;	
	2000	Harmi ganduatan anangu lahawatawall	IBM_TDB	2002/06/02 12:50
-	2089	"semiconductor energy laboratory"	USPĀT;	2003/06/03 13:52
	10706	Let on /Phin odd Eilm odd Eusandobout	US-PGPUB	2003/06/03 13:58
-	19706	tft or (thin adj film adj transistor)	USPAT;	2003/00/03 13:38
	641	(gottore) or gotton) and (tft or (this ad-	US-PGPUB	2003/06/03 14:00
-	641	(getter\$3 or getter) and (tft or (thin adj	USPAT;	2003/06/03 14:00
_	240	film adj transistor))	US-PGPUB USPAT;	2003/06/03 14:00
1 -	248	((getter\$3 or getter) and (tft or (thin adj film adj transistor))) not	USPAT; US-PGPUB	2003/06/03 14:00
	1	adj film adj transistor))) not   "semiconductor energy laboratory"	US-FGFUD	
I _	40	((((getter\$3 or getter) and (tft or (thin	USPAT;	2003/06/03 14:02
-	40	adj film adj transistor))) not	US-PGPUB	2003/00/03 14:02
		adj film adj transistor))) not   "semiconductor energy laboratory") and	US-FGFUD	
		@ad<20010216) and 438/\$.ccls.		
1_	111	(((getter\$3 or getter) and (tft or (thin	USPAT;	2003/06/03 18:03
1 -	1 111	adj film adj transistor))) not	US-PGPUB	2005,00,05 10:05
		"semiconductor energy laboratory") and	00 10100	
		Semiconductor energy laboratory / and     @ad<20010216		
1	1	680-50010510	1	t